

## SWIR Multichip Emitter & Detector

Product No: MTMD34679PD6T38

# Peak Emission Wavelengths: 1300,1460,1650,1720,1900nm Detector Sensitivity Wavelength Range: 600-2600nm

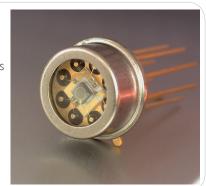
The MTMD34679PD6T38 is a SWIR multi-chip emitter with a InGaAs Photodiode designed for applications requiring various emission sources in a small, densley packaged area. These devices can be custom designed for specific wavelengths and outputs.

#### **FEATURES**

- > Hermetically Sealed TO-5 Metal Can Package
- > PIN Photodiode Chip Active Area: 1.0mm
- > High Output Power

#### **APPLICATIONS**

- > High Speed Communications
- > Medical / Chemical Analysis
- > Biofluorescense Analysis



ITEMS	SYMBOL			RATINGS			UNIT	
		1300	1460	1650	1720	1900		
Forward Current (DC)	IF	50	50	50	50	50	mA	
Forward Current (Pulse) *1	IFP						А	
Reverse Voltage	VR	5	5	5	5	5	V	
Power Dissipation	PD	50	50	50	50	50	mW	
Operating Temperature Range	Topr			-20~+8	35		°C	
Storage Temperature Range	Tstg			-30~+100			°C	
Junction Temperature	Tj			100			°C	
Lead Soldering Temperature *2	Tls			260			°C	

Emitter Electrica	l & Optical	Characteris	tics (Ta=25°C)				
ITEMS	SYMBOL	WAVELENGTH	GTH CONDITIONS		TYP	MAX	UNIT
Forward Voltage	VF	1300	IF=50mA		1.05		V
Forward Voltage	VF	1460	IF=50mA		1.02		V
Forward Voltage	VF	1650	IF=50mA		0.096		V
Forward Voltage	VF	1720	IF=50mA		0.096		V
Forward Voltage	VF	1900	IF=50mA		0.090		V
Reverse Current	IR		VR=5V			10	uA
Power Output	PO	1300	IF=50mA		4.8		mW
Power Output	PO	1460	IF=50mA		2.9		mW
Power Output	PO	1650	IF=50mA		2.7		mW
Power Output	PO	1720	IF=50mA		2.3		mW
Power Output	PO	1900	IF=50mA		1.9		mW

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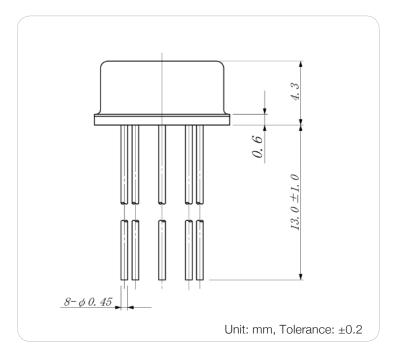


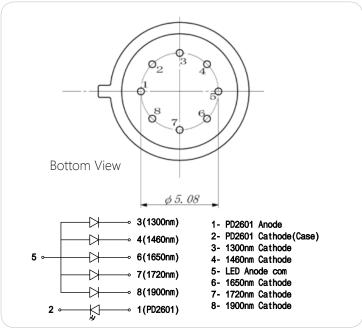
ITEMS	SYMBOL	WAVELENGTH	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Emission Wavelength	λр	1300	IF=50mA		1308		nm
Peak Emission Wavelength	λр	1460	IF=50mA		1460		nm
Peak Emission Wavelength	λр	1650	IF=50mA		1650		nm
Peak Emission Wavelength	λр	1720	IF=50mA		1741		nm
Peak Emission Wavelength	λр	1900	IF=50mA		1893		nm
Spectral Line Half Width	Δλ	1300	IF=50mA		76		nm
Spectral Line Half Width	Δλ	1460	IF=50mA		107		nm
Spectral Line Half Width	Δλ	1650	IF=50mA		135		nm
Spectral Line Half Width	Δλ	1720	IF=50mA		141		nm
Spectral Line Half Width	Δλ	1900	IF=50mA		160		nm

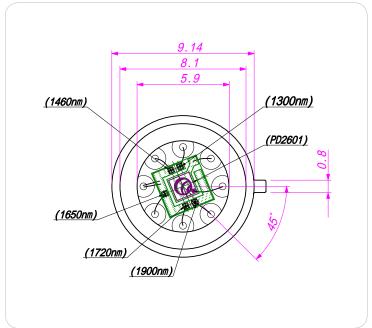
ITEMS	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Breakdown Voltage	VR	IR=100uA			1	V
Sensitivity Range	λ	VR=0V	600		2600	nm
Dark Current	ID	VR=1V			300	uA
Capacitance	C	VR=0V		1000		pF
Capacitance	C	VR=1V		85		pF
Responsivity	R	λ=2400nm		1.24		A/W
Shunt Resistance	RS	VR=10mV		3.3		MOhm
Quantum Efficiency	QE	λ=1840nm		72		%
Light Current @1300nm	IL	If=10mA		30		uA
ight Current @1300nm	IL	If=20mA		65		uA





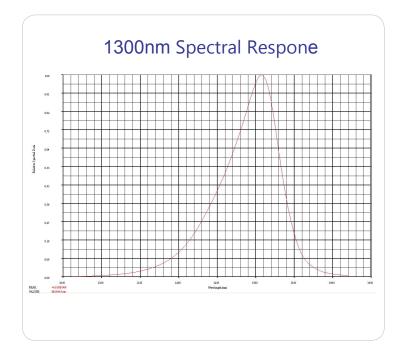


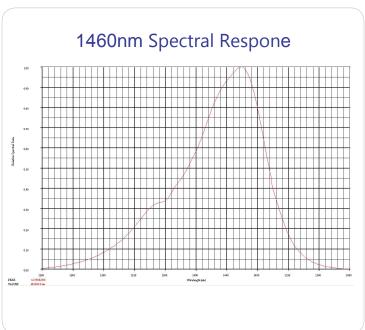


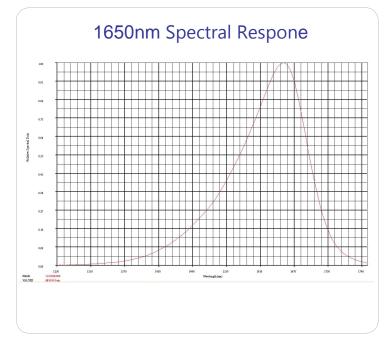


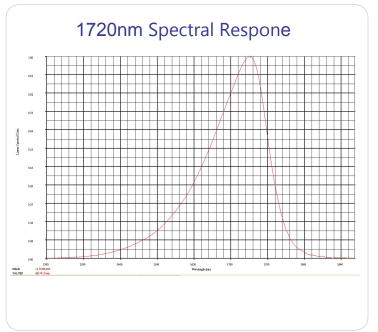


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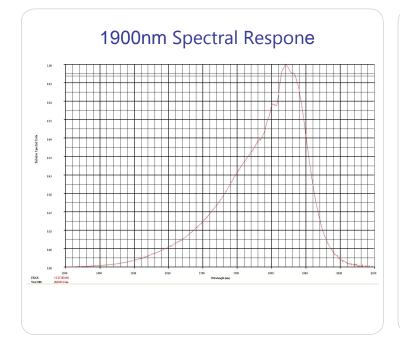


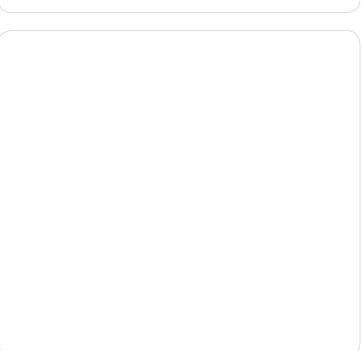






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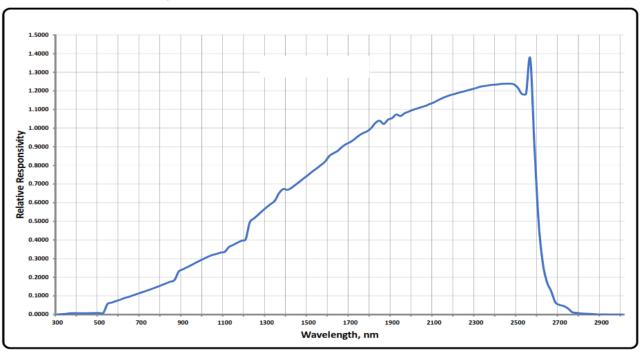


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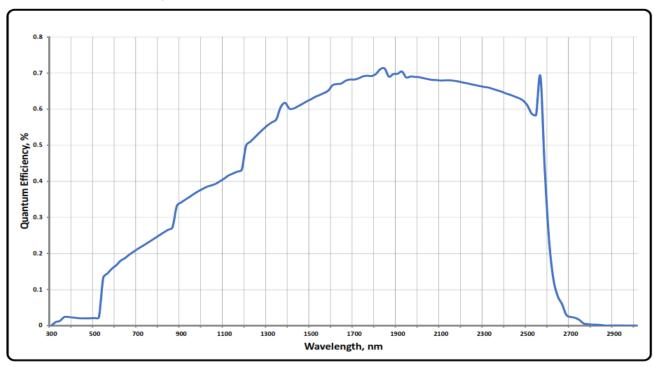




## **Spectral Responsivity**



### **Quantum Efficiency**



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